2SA1981

ŏHigh DC Current Gain
ŏTRANSISTOR (PNP)

Collector-Base Voltage		-35	V
Collector-Emitter Voltage	V_{CEO}		V
Emitter-Base Voltage		-5	V
Collector Current -Continuous			A
Collector Power Dissipation		625	
Thermal Resistance rom Junc tion to Ambient			℃ /W
Operation Junction and Storage Temperature Range			℃

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Base breakdown voltage	V(BR)CBO	IC=-B				V(BR)CBO